Vishay Semiconductors

650 V Power SiC Merged PIN Schottky Diode, 16 A



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LINKS TO ADDITIONAL RESOURCES

30	SPICE	
3D Models	Models	Application Notes

PRIMARY CHARACTERISTICS						
I _{F(AV)}	16 A					
V _R	650 V					
V _F at I _F at 150 °C	1.65 V					
T _J max.	175 °C					
I _R at V _R at 175 °C	10 µA					
Q _C (V _R = 400 V)	45 nC					
Package	2L TO-220AC					
Circuit configuration	Single					

FEATURES

 Majority carrier diode using Schottky technology on SiC wide band gap material



COMPLIANT HALOGEN

FREE

- \bullet Positive V_{F} temperature coefficient for easy paralleling
- · Virtually no recovery tail and no switching losses
- Temperature invariant switching behavior
- 175 °C maximum operating junction temperature
- MPS structure for high ruggedness to forward current surge events
- Meets JESD 201 class 1A whisker test
- Solder Bath temperature 275 °C maximum, 10 s per JESD 22-B106
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION / APPLICATIONS

Wide band gap SiC based 650 V Schottky diode, designed for high performance and ruggedness.

Optimum choice for high speed hard switching and efficient operation over a wide temperature range, it is also recommended for all applications suffering from Silicon ultrafast recovery behavior.

Typical applications include AC/DC PFC and DC/DC ultra high frequency output rectification in FBPS and LLC converters.

MECHANICAL DATA

Case: 2L TO-220AC

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

Mounting torque: 10 in-lbs maximum

ABSOLUTE MAXIMUM RATINGS ($T_A = 25 \text{ °C}$ unless otherwise specified)					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Peak repetitive reverse voltage	V _{RRM}		650	V	
Average rectified forward current	I _{F(AV)}	T _C = 121 °C (DC)	16	А	
DC blocking voltage	V _{DC}		650	V	
Repetitive peak surge current	I _{FRM}	T_C = 25 °C, f = 50 Hz, square wave, DC = 25 $\%$	55.5		
Non-repetitive peak forward surge current	I _{FSM}	T_{C} = 25 °C, t_{p} = 10 ms, half sine wave	120	A	
		T_{C} = 110 °C, t_{p} = 10 ms, half sine wave	110		
Power dissipation	P _{tot} ⁽¹⁾	T _C = 25 °C	89	w	
Fower dissipation	F tot \''	T _C = 110 °C	38	vv	
·0	∫i ² dt	T _C = 25 °C	72		
l ² t value	Jiat	T _C = 110 °C	61	A ² s	
Operating junction and storage temperatures	T _J ⁽²⁾ , T _{Stg}		-55 to +175	°C	

Notes

⁽¹⁾ Based on maximum R_{th}

 $^{(2)}$ The heat generated must be less than the thermal conductivity from junction-to-ambient: dP_D/dT_J < 1/R_{\rm 0JA}

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ELECTRICAL SPECIFICATIONS ($T_J = 25 \text{ °C}$ unless otherwise specified)							
PARAMETER	SYMBOL	SYMBOL TEST CONDITIONS MIN. TYP. MAX.					
		I _F = 16 A	-	1.45	1.70		
Forward voltage	V _F	I _F = 16 A, T _J = 150 °C	-	1.65	1.95	V	
		I _F = 16 A, T _J = 175 °C	-	1.75	-		
		$V_R = V_R$ rated	-	-	85		
Reverse leakage current	I _R	V _R = V _R rated, T _J = 150 °C	-	-	200	Αμ 00	
		V _R = V _R rated, T _J = 175 °C	-	10	-		
Tatal anna iteraa	С	V _R = 1 V, f = 1 MHz	-	700	-		
Total capacitance	U	V _R = 400 V, f = 1 MHz	-	71	-	pF	
Total capacitive charge	Q _C	V _R = 400 V, f = 1 MHz	-	45	-	nC	

THERMAL - MECHANICAL SPECIFICATIONS ($T_A = 25$ °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Thermal resistance, junction-to-case	R _{thJC}		-	1.3	1.7	°C/W	
Marking device				C16E	T07T		

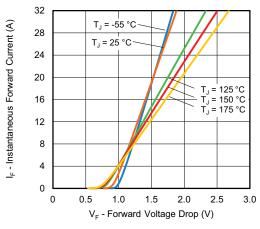


Fig. 1 - Typical Forward Voltage Drop Characteristics

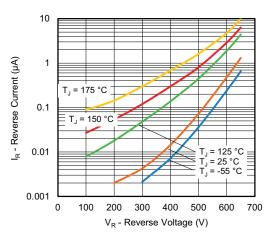


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

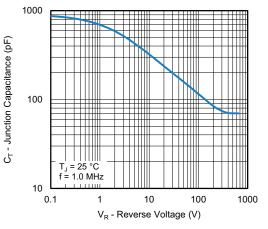


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

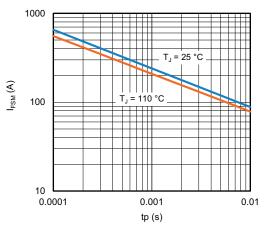
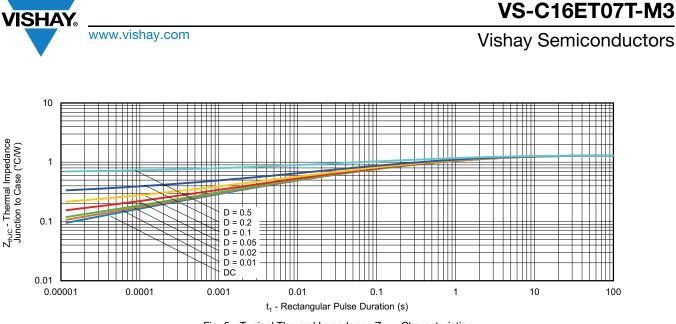
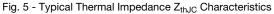
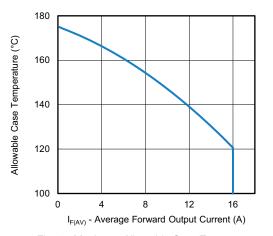


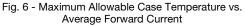
Fig. 4 - Non-Repetitive Peak Forward Surge Current vs. Pulse Duration (Square Wave)

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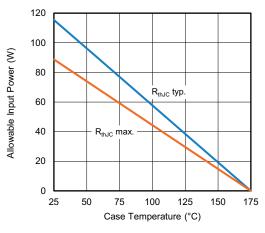


Fig. 7 - Forward Power Loss Characteristics

18 16 14 Capacitive Energy (µJ) 12 10 8 6 T_J = 25 °C f = 1.0 MHz 4 2 C V dV $E_I =$ 0 0 100 200 300 400 500 600 700 Reverse Voltage (V)

Fig. 8 - Typical Capacitive Energy vs. Reverse Voltage

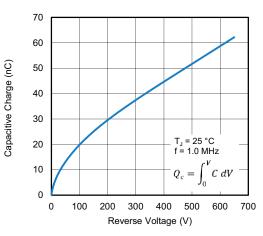


Fig. 9 - Typical Capacitive Charge vs. Reverse Voltage

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ORDERING INFORMATION TABLE

Device code	VS-	с	16	Е	т	07	т	-M3
		(2)	(3)	(4)	(5)	(6)		(8)
			\bigcirc	4	\bigcirc	\bigcirc	\mathbf{O}	U
	1	- Visl	nay Sem	niconduo	ctors pr	oduct		
	2 ·	- C =	SiC dio	de				
	3 -	- Cur	rent rati	ng (16 =	= 16 A)			
	4	- E=	single c	diode				
	5	- Pac	kage T	D-220				
	6	- Vol	tage rati	ng: (07	= 650 V)		
	7 -	• T =	true 2 p	in				
	8 -	- Env	ironmer	ntal digit				
		-M3	3 = halog	gen-free	, RoHS	-compli	ant, and	d termir

ORDERING INFORMATION							
PREFERRED P/N	BASE QUANTITY	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-C16ET07T-M3	50/tube	1000	Antistatic plastic tubes				

LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?96069			
Part marking information	www.vishay.com/doc?95391			
SPICE model	www.vishay.com/doc?96848			



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